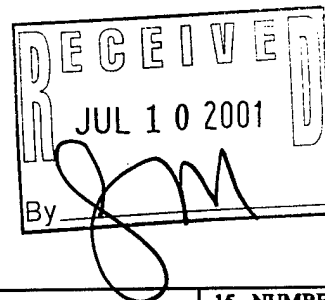


REPORT DOCUMENTATION PAGE

Form Approved
OMB NO. 0704-0188

Public Reporting burden for this collection of information is estimated to average 1 hour per response, including the time for reviewing instructions, searching existing data sources, gathering and maintaining the data needed, and completing and reviewing the collection of information. Send comment regarding this burden estimate or any other aspect of this collection of information, including suggestions for reducing this burden, to Washington Headquarters Services, Directorate for information Operations and Reports, 1215 Jefferson Davis Highway, Suite 1204, Arlington, VA 22202-4302, and to the Office of Management and Budget, Paperwork Reduction Project (0704-0188), Washington, DC 20503.

1. AGENCY USE ONLY (Leave Blank)		2. REPORT DATE	3. REPORT TYPE AND DATES COVERED Final 3/31/95-3/31/98 15 Apr 95-14 Jan 99
4. TITLE AND SUBTITLE Quantum Transport in Si/SiGe Nanostructures		5. FUNDING NUMBERS EL-33036 DAAH04-95-1-0191	
6. AUTHOR(S) Sean Washburn		8. PERFORMING ORGANIZATION REPORT NUMBER	
7. PERFORMING ORGANIZATION NAME(S) AND ADDRESS(ES) Dept Physics and Astronomy, Univ North Carolina at Chapel Hill Chapel Hill, NC 27599-3255		10. SPONSORING / MONITORING AGENCY REPORT NUMBER DAAH04-95-1-0191 33036.4-EL	
9. SPONSORING / MONITORING AGENCY NAME(S) AND ADDRESS(ES) U. S. Army Research Office P.O. Box 12211 Research Triangle Park, NC 27709-2211		11. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not be construed as an official Department of the Army position, policy or decision, unless so designated by other documentation.	
12 a. DISTRIBUTION / AVAILABILITY STATEMENT Approved for public release; distribution unlimited.		12 b. DISTRIBUTION CODE	
13. ABSTRACT (Maximum 200 words) The project to study quantum transport in Si/SiGe heterostructures has, in addition to attacking the proposed goals, emphasized work on the two-dimensional metal-insulator transition. Ballistic Aharonov-Bohm devices were made and studied. The experimental results on the metal-insulator complement and sharply contrast with the results from much lower mobility systems like Si-MOSFETs. Data can be scaled according to an equation drawn from considerations of zero-temperature quantum critical points, but with a much larger conductivity (by a factor of nearly 100) than in the more generic (lower) mobility samples.			
14. SUBJECT TERMS		15. NUMBER OF PAGES 3	
		16. PRICE CODE	
17. SECURITY CLASSIFICATION OR REPORT UNCLASSIFIED	18. SECURITY CLASSIFICATION ON THIS PAGE UNCLASSIFIED	19. SECURITY CLASSIFICATION OF ABSTRACT UNCLASSIFIED	20. LIMITATION OF ABSTRACT UL



NSN 7540-01-280-5500

Standard Form 298 (Rev.2-89)
Prescribed by ANSI Std. Z39-18
298-102

20010725 018

REPORT DOCUMENTATION PAGE (SF298) (Continuation Sheet)

The specific original goal was an attempt to fabricate and study quantum wires and to use them to attack four problems in quantum transport:

- (1) study of ballistic transport in point contacts,
- (2) study Aharonov-Bohm interference in loops,
- (3) begin studies of Luttinger correlations in one-dimensional transport and
- (4) study of electrostatic effects in quantum interference.

The first two of these targets were accomplished, and the results are published two refereed articles:

"Observation of ballistic conductance and Aharonov-Bohm Oscillations in Si/SiGe heterostructures," *Applied Physics Letters*, **6** (1994) pp 3114-6, WX Gao, K Ismail, KY Lee, JO Chu and S Washburn;

"Fabrication of Aharonov-Bohm rings in Si/SiGe heterostructures," *Microelectronic Engineering*, **2** (1995) pp 79-82, KY Lee, K Ismail, JO Chu, WX Gao and S Washburn.

In these experiments small wires (widths down to $0.2\mu\text{m}$) were wet or reactive ion etched into the cap and dopant layers of a high-mobility heterostructure. Schottky gates were then deposited across parts of the channel or over the entire device to permit carrier concentration in the conducting channels to be modulated. Ballistic channel widths down to less than $0.3\mu\text{m}$ could be formed in this fashion. A back-gated permitted carrier concentration control in the entire device. Some details of the research have been given in previous annual reports as well.

The third target was also covered in the same experiments, but with no dramatic revelations about the correlated motion of the carriers. Hence no separate publications were submitted as the results did not warrant dissemination. Some of the results have been mentioned as illustrative data in publications such as:

"Some consequences of chaos for quantum devices," in *Quantum Based Electronic Devices and Systems*, ed: MA Strosio and M Dutta (World Scientific, Singapore, 1998); Int J High Speed Electron Syst, **9**, 209-22 (1998). S Washburn.

"Resource Letter QIMS-1: Quantum Interference in Macroscopic Samples," *Am J Phys*, **63**, 683--93 (1995). (invited) S Das Sarma, T Kawamura and S Washburn.

The fourth target consumed much of the time. It was discovered during the course of the grant that the moderately high-mobility two dimensional electron or hole systems are behaving as if the carriers undergo a transition from the insulating behavior expected for non-interacting carriers (where conductivity decreases with decreasing temperature) to a metallic "state" where the opposite trend appears. This appears to be an extension of granular systems in which a superconductor-insulator transition has been studied since the late 1980's. The following publications contain the results from these experiments.

"Metal-Insulator Transition in Two Dimensions: Effects of Disorder and Magnetic Field," *Phys Rev Lett*, **79**, 1543-6 (1997). D Popovic, A Fowler and S Washburn.

Comment on "Electric Field Scaling at $B=0$ Metal-Insulator Transition in Two Dimensions," cond-mat/9707061. K Ismail, JO Chu, D Popovic, A Fowler and S Washburn.

"Conductance Fluctuations Near the Two-Dimensional Metal-Insulator Transition," Int. Conf. Electronic Properties of Two-Dimensional Systems, *Physica B*, **249-251**, 504-7 (1998). KP Li, D Popovic and S Washburn.

"Metal-Insulator Transition in a low-mobility two-dimensional electron gas," Int. Conf. Electronic Properties of Two-Dimensional Systems, *Physica B*, **249-251**, 701-4 (1998). D Popovic, AB Fowler and S Washburn.

“Absence of Localization in Certain Field Effect Transistors,” *Superlattices and Microstructures*, **23**, 581-91 (1998). (invited) S Washburn, D Popovic, KP Li and AB Fowler.

“Scaling and universal behavior near the two-dimensional metal-insulator transition” Proc. 22nd Int School Theoretical Physics, Ustron, 10-15 Sept 1998; *Mol Phys Rept*, **24**, 150-7 (1999). (invited) S Washburn, NJ Kim, KP Li and D Popovic.

In addition to the publications, the grant supported the final year of PhD training for WX Gao (now employed at SGS-Thomson), and the first two years of the training for NJ Kim (accepted a postdoc at Case Western Reserve) who will defend his dissertation later this month. It also provided partial support for travel to conferences and contributed talks by the students once each year as well as partial support for the PI to deliver invited lectures at NC State University, University of Cincinnati, University of Virginia and the 22nd International School of Theoretical Physics.

MASTER COPY: PLEASE KEEP THIS "MEMORANDUM OF TRANSMITTAL" BLANK FOR REPRODUCTION PURPOSES. WHEN REPORTS ARE GENERATED UNDER THE ARO SPONSORSHIP, FORWARD A COMPLETED COPY OF THIS FORM WITH EACH REPORT SHIPMENT TO THE ARO. THIS WILL ASSURE PROPER IDENTIFICATION. NOT TO BE USED FOR INTERIM PROGRESS REPORTS; SEE PAGE 2 FOR INTERIM PROGRESS REPORT INSTRUCTIONS.

MEMORANDUM OF TRANSMITTAL

U.S. Army Research Office
ATTN: AMXRO-ICA (Hall)
P.O. Box 12211
Research Triangle Park, NC 27709-2211

☐ Reprint (Orig + 2 copies)

☒ Technical Report (Orig + 2 copies)

☐ Manuscript (1 copy)

☒ Final Progress Report (Orig + 2 copies)

☐ Related Materials, Abstracts, Theses (1 copy)


CONTRACT/GRANT NUMBER: 33036-EL

REPORT TITLE: QuantumTransport in Si/SiGe Nanostructures

is forwarded for your information.

SUBMITTED FOR PUBLICATION TO (applicable only if report is manuscript):

Sincerely,

A handwritten signature in black ink, appearing to be "J. Hall", followed by a horizontal line.

Enclosure 3

FORECAST EXPENDITURE REPORT
(IMPORTANT!>>>YOU MUST REPLY TO RECEIVE ADDITIONAL FUNDING<<<)

The research agreement identified below is under consideration for additional funding. The contemplated funding, resulting in an extension to the performance period of the agreement, is consistent with the terms and conditions of the agreement. Before a decision can be made to provide the additional funding, the following information is needed: (i) an accounting of costs incurred to date and (ii) a projection of financial needs for the period of the agreement extension. Please complete SECTION 2, below **within 30 days of receipt of this request** and return to: U.S. Army Research Office, ATTN: (Name provided by ARO) P.O. Box 12211, Research Triangle Park, North Carolina, 27709-2211.

SECTION 1: GENERAL INFORMATION

<p>ARO Proposal Number: <u>(Provided by ARO)</u> Agreement Number: <u>(Provided by ARO)</u> Agreement Period: <u>(Provided by ARO)</u> From To <u>(provided by ARO)</u> Recipient: <u>(Provided by ARO)</u> Principal Investigator: <u>(Provided by ARO)</u> Planned Period of Extension for: (No of Mos.) months beginning <u>(Provided by ARO)</u> ARO Technical Monitor: <u>(Provided by ARO)</u> ARO Technical Monitor's E-mail: <u>(Provided by ARO)</u></p>	<p>Award Amount: (\$ provided by ARO) Funded Amount: (\$ provided by ARO) Period Funded Through <u>(Provided by ARO)</u> Planned Funding: <u>(Provided by ARO)</u> Monitor's Phone #: <u>(Provided by ARO)</u></p>
--	--

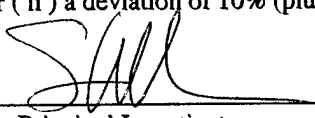
SECTION 2: ACCOUNTING AND FORECASTING OR EXPENDITURES

Payments to Date: \$ (Provided by ARO)

- | | |
|--|-----------------|
| 1. Expenditures (cost incurrances from date of contract/grant initiation) as of date of receipt of this request or as of most recent cutt-off in accounting records: | \$ <u>90000</u> |
| 2. Additional projected expenditures before (date entered by ARO) | \$ _____ |
| 3. Total of items 1 and 2: | \$ _____ |
| 4. Forecast expenditures for the proposed <u>(number)</u> months period of extension: | \$ _____* |

* The forecast cannot exceed the planned level of funding identified in SECTION 1. If the forecast expenditures differ significantly from the budget previously negotiated and included in the research agreement, a new budget must be submitted. A "significantly different" budget is defined as (i) a decrease in the planned funding level cited above or (ii) a deviation of 10% (plus or minus) to any cost element (direct labor, indirect expense, travel, etc.) included in the budget.

Date: 6 July 01

Signature 
Principal Investigator

SECTION 3: FOR U.S. ARMY RESEARCH OFFICE USE ONLY

☐ Recommend funding at level cited in SECTION 1, above.

☐ Recommend no additional funds be provided at this time.

☐ Recommend funding consistent with revised budget of Principal Investigator.

☐ Recommend extension of agreement through _____ without additional funds.

☐ Recommend funding in amount of \$ _____

☐ Other (Explanation attached).

Date: _____

Signature _____
Technical Monitor